Level Translator, 1-Bit Bidirectional

Configurable Voltage Supplies and Bushold Data Inputs

The FXLH1T45 is a single bit configurable dual-voltage supply translator designed for both uni-directional and bi-directional voltage translation between two logic levels. The device allows translation between voltages as high as 3.6 V to as low as 1.1 V. The A port tracks the V_{CCA} level, and the B port tracks the V_{CCB} level. This allows for bi-directional voltage translation over a variety of voltage levels: 1.2 V, 1.5 V, 1.8 V, 2.5 V and 3.3 V.

The device remains in 3–STATE until both V_{CC} s reach active levels allowing either V_{CC} to be powered-up first. Internal power down control circuits place the device in 3–STATE if either V_{CC} is removed.

The Transmit/Receive (T/\overline{R}) input determines the direction of data flow through the device. The FXLH1T45 is designed so that the control pin (T/\overline{R}) is supplied by V_{CCA} .

Features

- Bi-directional Interface between any 2 Levels from 1.1 V to 3.6 V
- Fully Configurable: Inputs Track V_{CC} level
- Non-preferential Power-up Sequencing; either V_{CC} may be Powered-up First
- Outputs Remain in 3-STATE until Active V_{CC} Level is Reached
- Outputs Switch to 3-STATE if either Vcc is at GND
- Power Off Protection
- Bushold On Data Inputs Eliminates the Need for External Pull-up/Pull-down Resistors
- Control Input (T/\overline{R}) Levels are Referenced to V_{CCA} Voltage
- Packaged in the MicroPak 6 SIP6 (1.0 mm x 1.45 mm)
- ESD Protections Exceeds:
 - 4 kV HBM ESD (per JESD22-A114 & Mil Std 883e 3015.7)
 - 8 kV HBM I/O to GND ESD (per JESD22-A114 & Mil Std 883e 3015.7)
 - 1 kV CDM ESD (per ESD STM 5.3)
 - 200 V MM ESD (per JESD22-A115 & ESD STM5.2)



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SIP6 1.45x1.0 CASE 127EB

MARKING DIAGRAM

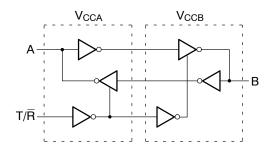


XD	= Device Code
KK	= Lot Code
XY	= Numeric Date Code
Z	= Assembly Plant Code

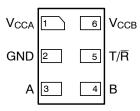
ORDERING INFORMATION

See detailed ordering and shipping information on page 9 of this data sheet

FUNCTIONAL DIAGRAM



PINOUT



(Top Through View)

PIN ASSIGNMENT

Pin Number	Terminal Name
1	V _{CCA}
2	GND
3	A
4	В
5	T/R
6	V _{CCB}

PIN DESCRIPTIONS

Pin Names	Description
T/R	Transmit/Receive Input
A	Side A Input or Output
В	Side B Input or Output
V _{CCA}	Side A Power Supply
V _{CCB}	Side B Power Supply

FUNCTION TABLE

Inputs (T/R)	Outputs
L	Bus B Data to Bus A
Н	Bus A Data to Bus B

H = HIGH Logic Level L = LOW Logic Level

POWER-UP/POWER-DOWN SEQUENCING

FXL translators offer an advantage in that either V_{CC} may be powered up first. This benefit derives from the chip design. When either V_{CC} is at 0V, outputs are in a HIGH–Impedance state. To ensure that bus contention, excessive currents, or oscillations do not occur, a proper power–up sequence is recommended.

The recommended power-up sequence is the following:

- 1. Apply power to either V_{CC}
- 2. Apply power to the T/R input (Logic HIGH for A-to-B operation; Logic LOW for B-to-A operation) and to the respective data inputs (A Port or B Port). This may occur at the same time as Step 1
- 3. Apply power to other V_{CC}

The recommended power-down sequence is the following:

- 4. Remove power from either V_{CC}
- 5. Remove power from other V_{CC}

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Rating
V _{CCA} , V _{CCB}	Supply Voltage	−0.5 V to +4.6 V
Vı	DC Input Voltage I/O Port A I/O Port B Control Input (T/R)	-0.5 V to +4.6 V -0.5 V to +4.6 V -0.5 V to +4.6 V
Vo	Output Voltage (Note 1) Outputs 3-STATE Outputs Active (A _n) Outputs Active (B _n)	-0.5 V to +4.6 V -0.5 V to V _{CCA} + 0.5 V -0.5 V to V _{CCB} + 0.5 V
l _{IK}	DC Input Diode Current @ V _I < 0 V	–50 mA
Іок	DC Output Diode Current @ V _O < 0 V V _O > V _{CC}	–50 mA +50 mA
I _{OH} / I _{OL}	DC Output Source/Sink Current	–50 mA / +50 mA
I _{CC}	DC V _{CC} or Ground Current per Supply Pin	±100 mA
T _{STG}	Storage Temperature Range	−65°C to +150°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS (Note 2)

Symbol	Parameter	Rating
V _{CCA} or V _{CCB}	Power Supply Operating	1.1 V to 3.6 V
Vi	Input Voltage Port A Port B Control Input (T/R)	0.0 V to 3.6 V 0.0 V to 3.6 V 0.0 V to V _{CCA}
Vo	Output Current in I _{OH} /I _{OL} with V _{CC @} 3.0 V to 3.6 V 2.3 V to 2.7 V 1.65 V to 1.95 V 1.4 V to 1.65 V 1.1 V to 1.4 V	±24 mA ±18 mA ±6 mA ±2 mA ±0.5 mA
T _A	Free Air Operating Temperature	-40°C to +125°C
Δt/ ΔV	Maximum Input Edge Rate V _{CCA/B} = 1.1 V to 3.6 V	10 ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

- 1. I_O Absolute Maximum Rating must be observed.
- 2. All unused inputs and I/O pins must be held at V_{CCI} or GND.

DC ELECTRICAL CHARACTERISTICS $(T_A = -40^{\circ}C \text{ to } +125^{\circ}C, \text{ unless otherwise noted. Typical values are at } T_A = +25^{\circ}C)$

Symbol	Parameter	Conditions	V _{CCI} (V)	V _{CCO} (V)	Min.	Тур.	Max.	Units
V _{IH}	High Level Input Voltage	Data Inputs A _n , B _n	2.7–3.6	1.1–3.6	2.0	-	-	V
	(Note 3)		2.3–2.7		1.6	-	-	
			1.65-2.3		0.65 x V _{CCI}	-	-	
			1.4–1.65		0.65 x V _{CCI}	-	=	
			1.1–1.4		0.9 x V _{CCI}	-	_	
		Control Pin T/R	2.7–3.6	1.1–3.6	2.0	-	-	
		(Referenced to V _{CCA})	2.3–2.7		1.6	-	-	
			1.65-2.3		0.65 x V _{CCA}	-	-	
			1.4–1.65		0.65 x V _{CCA}	-	-	
			1.1–1.4		0.9 x V _{CCA}	-	_	
V _{IL}	Low Level Input Voltage	Data Inputs A _n , B _n	2.7–3.6	1.1–3.6	_	-	0.8	V
	(Note 3)		2.3–2.7		-	-	0.7	
			1.65–2.3		_	-	0.35 x V _{CCI}	
			1.4–1.65		-	-	0.35 x V _{CCI}	
			1.1–1.4		-	-	0.1 x V _{CCI}	
		Control Pin T/R	2.7–3.6	1.1–3.6	_	-	0.8	
	(Referenced to V _{CCA})	2.3–2.7		-	-	0.7		
			1.65–2.3		_	-	0.35 x V _{CCA}	
			1.4–1.65		_	-	0.35 x V _{CCA}	
			1.1–1.4		_	-	0.1 x V _{CCA}	
V _{OH}	High Level Output Voltage	I _{OH} = -100 μA	1.1–3.6	1.1–3.6	V _{CCO} -0.2	-	_	V
	(Note 4)	I _{OH} = -12 mA	2.7	2.7	2.2	-	-	
		$I_{OH} = -18 \text{ mA}$	3.0	3.0	2.4	-	-	
		$I_{OH} = -24 \text{ mA}$	3.0	3.0	2.2	-	-	
		$I_{OH} = -6 \text{ mA}$	2.3	2.3	2.0	-	-	
		I _{OH} = -12 mA	2.3	2.3	1.8	-	-	
		$I_{OH} = -18 \text{ mA}$	2.3	2.3	1.7	-	-	
		$I_{OH} = -6 \text{ mA}$	1.65	1.65	1.25	-	-	
		$I_{OH} = -2 \text{ mA}$	1.4	1.4	1.05	-	-	
		$I_{OH} = -0.5 \text{ mA}$	1.1	1.1	0.75 x V _{CCO}	-	-	
V _{OL}	Low Level Output Voltage (Note 4)	$I_{OL} = 100 \mu A$	1.1–3.6	1.1–3.6	-	-	0.2	V
	(Note 4)	I _{OL} = 12 mA	2.7	2.7	_	-	0.4	
		I _{OL} = 18 mA	3.0	3.0	-	-	0.4	
		I _{OL} = 24 mA	3.0	3.0	-	-	0.55	
		I _{OL} =12 mA	2.3	2.3	_		0.4	
		I _{OL} = 18 mA	2.3	2.3	_	-	0.6	
		I _{OL} = 6 mA	1.65	1.65	_	-	0.3	
		I _{OL} = 2 mA	1.4	1.4	_	-	0.35	
		I _{OL} = 0.5 mA	1.1	1.1	=	-	0.3 x V _{CCO}	
lį	Input Leakage Current Control Pins	$V_I = V_{CCA}$ or GND	1.1–3.6	3.6	-	_	±1.0	μΑ

DC ELECTRICAL CHARACTERISTICS (continued) ($T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$)

Symbol	Parameter	Conditions	V _{CCI} (V)	V _{CCO} (V)	Min.	Тур.	Max.	Units
I _{I(HOLD)}	Bushold Input Minimum Drive Current	$V_{IN} = 0.8 \text{ V},$ $T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	3.0	3.0	75.0	-	-	μА
		V _{IN} = 0.8 V	3.0	3.0	60.0	-	-	
		$V_{IN} = 2 V,$ $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	3.0	3.0	-75.0	-	-	
		V _{IN} = 2 V	3.0	3.0	-60	_	_	
		V _{IN} = 0.7 V	2.3	2.3	45.0	_	-	
		V _{IN} = 1.6 V	2.3	2.3	-45.0	_	-	
		V _{IN} = 0.57 V	1.65	1.65	25.0	_	-	
		V _{IN} = 1.07 V	1.65	1.65	-25.0	_	-	
		V _{IN} = 0.49 V	1.4	1.4	10.0	_	-	
		V _{IN} = 0.91 V	1.4	1.4	-10.0	_	-	
		V _{IN} = 0.11 V	1.1	1.1	-	4.0	-	
		V _{IN} = 0.99 V	1.1	1.1	-	-4.0	-	
I _{I(OD)}	Bushold Input Over-Drive	(Note 5)	3.6	3.6	450	_	-	μΑ
	Current-to-Change State	(Note 6)	3.6	3.6	-450	_	=	
		(Note 5)	2.7	2.7	300	_	_	
		(Note 6)	2.7	2.7	-300	_	_	
		(Note 5)	1.95	1.95	200	_	=	
		(Note 6)	1.95	1.95	-200	_	_	
		(Note 5)	1.6	1.6	120	_	=	
		(Note 6)	1.6	1.6	-120	_	=	
		(Note 5)	1.4	1.4	80.0	_	=	
		(Note 6)	1.4	1.4	-80.0	-	=	
I _{OFF}	Power Off Leakage Current	$\begin{array}{l} A_n, V_{CCA} = V_{CCI}, \\ V_I = 0 V to 3.6 V \end{array}$	0	3.6	-	-	±10.0	μΑ
		$B_n, V_{CCB} = V_{CCI},$ $V_I = 0 \text{ V to } 3.6 \text{ V}$	0	3.6	-	-	±10.0	
I _{OZ}	3-STATE Output Leakage	$\begin{array}{l} A_n, \ V_{CCA} = V_{CCO}, \\ V_O = 0 \ V \ or \ 3.6 \ V \end{array}$	0	3.6	_	-	±10.0	μΑ
		$B_n, V_{CCB} = V_{CCO},$ $V_O = 0 \text{ V or } 3.6 \text{ V}$	0	3.6	-	_	±10.0	
I _{CCA/B}	Quiescent Supply Current (Note 7)	$V_I = V_{CCI}$ or GND; $I_O = 0$	1.1–3.6	1.1–3.6	-	-	20.0	μΑ
I _{CCA}	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$	0	1.1–3.6	=	-	-10.0	μΑ
		$V_I = V_{CCA}$ or GND; $I_O = 0$	1.1–3.6	0	=	-	10.0	
I _{CCB}	Quiescent Supply Current	$V_I = V_{CCB}$ or GND; $I_O = 0$	1.1–3.6	0	_	_	-10.0	μΑ
		$V_I = V_{CCB}$ or GND; $I_O = 0$	0	1.1–3.6	_	_	10.0	7
ΔI _{CCA/B}	Increase in I _{CC} per Input; Other Inputs at V _{CC} or GND	V _{IH} = 3.0 V	3.6	3.6	_	-	500	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. NOTES:

- V_{CCI} = the V_{CC} associated with the data input under test.
 V_{CCO} = the V_{CC} associated with the output under test.
 An external driver must source at least the specified current to switch LOW-to-HIGH.
 An external driver must source at least the specified current to switch HIGH-to-LOW.
- 7. Reflects current per supply, V_{CCA} or V_{CCB} .

 $\textbf{AC Electrical Characteristics} \ (T_A = -40^{\circ}C \ to \ +125^{\circ}C, \ unless \ otherwise \ noted. \ Typical \ values \ are \ at \ T_A = +25^{\circ}C.)$

V_{CCA} = 3.0 V to 3.6 V

		V _{CC} 3.0 V to	c _B = o 3.6 V	V _{CC} 2.3 V to	:в = 5 2.7 V		V _{CCB} = 1.65 V to 1.95 V		V _{CCB} = 1.4 V to 1.6 V		V _{CCB} = 1.1 V to 1.3 V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.2	3.5	0.3	3.9	0.5	5.4	0.6	6.8	1.4	22.0	ns
	Propagation Delay B to A	0.2	3.5	0.2	3.8	0.3	4.0	0.5	4.3	0.8	13.0	
t _{PZH} , t _{PZL} (Note 8)	Output Enable T/\overline{R} to B	0.4	7.2	0.5	7.6	0.7	9.1	0.8	10.5	1.6	25.7	ns
(Note 6)	Output Enable T/R to A	0.4	7.3	0.4	7.8	1.0	8.8	2.0	10.5	2.8	30.0	
t _{PHZ} , t _{PLZ}	Output Disable T/R to B	-	3.9	-	5.3	_	7.3	-	7.6	_	17.0	ns
	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	-	5.6	-	4.2	_	6.3	-	6.9	_	17.0	
	Output Disable T/R to A	-	4.9	-	5.8	-	3.7	-	5.7	-	3.7	
	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	-	4.6	-	4.8	-	4.5	-	4.9	-	4.5	

V_{CCA} = 2.3 V to 2.7 V

		V _{CCB} = 3.0 V to 3.6 V		V _{CCB} = 2.3 V to 2.7 V		V _{CCB} = 1.65 V to 1.95 V		V _{CCB} = 1.4 V to 1.6 V		V _{CCB} = 1.1 V to 1.3 V		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.2	3.8	0.4	4.2	0.5	5.6	0.8	6.9	1.4	22.0	ns
	Propagation Delay B to A	0.3	3.9	0.4	4.2	0.5	4.5	0.5	4.8	1.0	7.0	
t _{PZH} , t _{PZL} (Note 8)	Output Enable T/R to B	0.4	7.8	0.6	8.2	0.7	9.6	1.0	10.9	1.6	26.0	ns
(14010-0)	Output Enable T/R to A	0.5	8.0	0.6	8.5	1.2	9.3	2.0	11.5	3.0	24.0	
t _{PHZ} , t _{PLZ}	Output Disable T/R to B	-	4.1	-	4.3	-	7.0	-	6.7	_	17.0	ns
	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	-	5.7	-	4.3	-	5.7	-	6.7	-	17.0	
	Output Disable T/R to A	-	5.3	-	5.9	-	4.0	-	6.0	-	5.9	
	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	-	4.8	-	4.8	-	4.8	-	5.0	_	4.8	

V_{CCA} = 1.65 V to 1.95 V

			V _{CCB} = 3.0 V to 3.6 V		V _{CCB} = 2.3 V to 2.7 V		V _{CCB} = 1.65 V to 1.95 V		V _{CCB} = 1.4 V to 1.6 V		V _{CCB} = 1.1 V to 1.3 V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
TETT THE	Propagation Delay A to B	0.3	4.0	0.5	4.5	0.8	5.7	0.9	7.1	1.5	22.0	ns
	Propagation Delay B to A	0.5	5.4	0.5	5.6	0.8	5.7	1.0	6.0	1.2	8.0	
t _{PZH} , t _{PZL} (Note 8)	Output Enable T/R to B	0.8	9.0	1.0	9.5	1.3	10.7	1.4	12.1	2.0	27.0	ns
(Note 8)	Output Enable T/R to A	0.7	10.5	0.7	10.8	1.6	10.9	2.5	13.0	3.2	25.0	
t _{PHZ} , t _{PLZ}	Output Disable T/R to B	-	5.1	-	5.2	-	6.7	-	7.0	-	17.0	ns
	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	-	5.7	-	5.6	-	5.8	-	7.0	_	17.0	
	Output Disable T/R to A	-	5.0	-	6.5	-	5.0	-	5.0	-	5.0	
	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	-	5.0	_	5.0	_	5.0	-	5.0	_	5.0	

 $V_{CCA} = 1.4 \text{ V to } 1.6 \text{ V}$

		V _{CCB} = 3.0 V to 3.6 V		V _{CCB} = 2.3 V to 2.7 V		V _{CCB} = 1.65 V to 1.95 V		V _{CCB} = 1.4 V to 1.6 V		V _{CCB} = 1.1 V to 1.3 V		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.5	4.3	0.5	4.8	1.0	6.0	1.0	7.3	1.5	22.0	ns
	Propagation Delay B to A	0.6	6.8	0.8	6.9	0.9	7.1	1.0	7.3	1.3	9.5	
t _{PZH} , t _{PZL} (Note 8)	Output Enable T/\overline{R} to B	1.5	10.3	1.5	10.8	2.0	12.0	2.0	13.3	2.5	28.0	ns
	Output Enable T/R to A	1.0	12.9	1.2	13.1	1.8	13.3	2.5	14.8	3.3	27.5	
t _{PHZ} , t _{PLZ}	Output Disable T/R to B	-	6.1	-	6.2	-	6.2	-	7.5	_	18.0	ns
	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	-	6.1	_	6.2	-	6.2	-	7.5	_	18.0	
	Output Disable T/R to A	-	8.0	_	7.5	-	6.0	-	6.0	_	6.0	
	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	ı	6.5	-	6.3	-	6.0	-	6.0	-	6.0	

V_{CCA} = 1.1 V to 1.3 V

		V _{CC} 3.0 V to	CB = 0 3.6 V	V _{CC} 2.3 V to		V _{CCB} = to 1.			CB = 0 1.6 V	V _{CC} 1.1 V to		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.8	13.0	1.0	7.0	1.2	8.0	1.3	9.5	2.0	24.0	ns
	Propagation Delay B to A	1.4	22.0	1.4	22.0	1.5	22.0	1.5	22.0	2.0	24.0	
t _{PZH} , t _{PZL} (Note 8)	Output Enable T/R to B	2.8	28.0	3.0	19.0	3.2	20.0	3.3	21.5	4.0	36.0	ns
(14010-0)	Output Enable T/R to A	2.4	37.0	2.1	29.0	2.5	30.0	3.5	32.0	4.0	44.0	
t _{PHZ} , t _{PLZ}	Output Disable T/R to B	-	15.0	_	7.0	-	8.0	-	10.0	_	20.0	ns
	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	-	15.0	_	7.0	-	8.0	_	10.0	_	20.0	
	Output Disable T/R to A	ı	15.0	_	12.0	_	12.0	_	12.0	_	12.0	
	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	-	15.0	_	12.0	-	12.0	_	12.0	_	12.0	

NOTES:

8. The enable time, t_{PZH} or t_{PZL}, is the time for the FXLH1T45 to return to active operation after a direction change. The enable time specifies the worst-case delay from the time the T/R pin is switched until a valid output signal is expected. For example, to change direction to B-to-A operation, the T/R pin is switched from HIGH-to-LOW. The enable time for this case is found by adding the disable time for T/R to B to the operation, the T/R pin is switched from High-to-Low. The enable time for this case is to propagation delay for B to A. The formulas for calculating enable times are the following: $t_{PZH}\left(T/\overline{R} \text{ to A}\right) = t_{PLZ}\left(T/\overline{R} \text{ to B}\right) + t_{PLH}\left(B \text{ to A}\right) \\ t_{PZL}\left(T/\overline{R} \text{ to A}\right) = t_{PLZ}\left(T/\overline{R} \text{ to B}\right) + t_{PLH}\left(B \text{ to A}\right) \\ t_{PZH}\left(T/\overline{R} \text{ to B}\right) = t_{PLZ}\left(T/\overline{R} \text{ to A}\right) + t_{PLH}\left(A \text{ to B}\right) \\ t_{PZL}\left(T/\overline{R} \text{ to B}\right) = t_{PLZ}\left(T/\overline{R} \text{ to A}\right) + t_{PHL}\left(A \text{ to B}\right)$

CAPACITANCE

			T _A = +25°C	
Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance Control Pin (T/R)	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCA/B}$	4.0	pF
C _{I/O}	Input/Output Capacitance A _n , B _n Ports	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCA/B}$	5.0	pF
C _{PD}	Power Dissipation Capacitance	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CC}, F = 10 \text{ MHz}$	20.0	pF

AC Loading and Waveforms

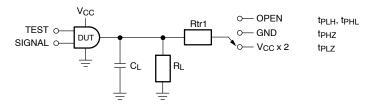


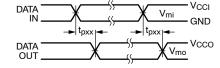
Figure 1. AC Test Circuit

AC TEST CIRCUIT

Test	Switch
t _{PLH} , t _{PHL}	OPEN
t _{PLZ}	V_{CCO} x 2 at V_{CCO} = 3.3 \pm 0.3 V, 2.5 V \pm 0.2 V, 1.8 V \pm 0.15 V, 1.5 V \pm 0.1 V, 1.2 V \pm 0.1 V
t _{PHZ}	GND

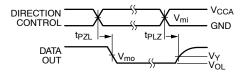
AC LOAD TABLE

V _{cco}	CL	R_L	Rtr1
1.2 V ±0.1 V	15 pF	2 kΩ	2 kΩ
1.5 V ±0.1 V	15 pF	2 kΩ	2 kΩ
1.8 V ±0.15 V	15 pF	2 kΩ	2 kΩ
2.5 V ±0.2 V	15 pF	2 kΩ	2 kΩ
3.3 V ±0.3 V	15 pF	2 kΩ	2 kΩ



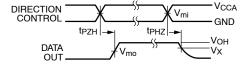
Input $t_R=t_F=2.0$ ns, 10% to 90% Input $t_R=t_F=2.5$ ns, 10% to 90%, @ V $_I=3.0$ V to 3.6 V only

Figure 2. Waveform for Inverting and Non-Inverting Functions



Input t_R = t_F = 2.0 ns, 10% to 90% Input t_R = t_F = 2.5 ns, 10% to 90%, @ V $_I$ = 3.0 V to 3.6 V only

Figure 3. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic



Input $t_R = t_F = 2.0$ ns, 10% to 90% Input $t_R = t_F = 2.5$ ns, 10% to 90%, @ $V_I = 3.0$ V to 3.6 V only

Figure 4. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

		V _{CC}					
Symbol	3.3V ± 0.3V	2.5 V ± 0.2 V	1.8 V ± 0.15 V	1.5 V ± 0.1 V	1.2 V ± 0.1 V		
V _{mi}	V _{CCI} / 2	V _{CCI} / 2	V _{CCI} / 2	V _{CCI} / 2	V _{CCI} / 2		
V _{mo}	V _{CCO} / 2	V _{CCO} / 2	V _{CCO} / 2	V _{CCO} / 2	V _{CCO} / 2		
V _X	V _{OH} – 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V	V _{OH} - 0.1 V	V _{OH} – 0.1 V		
V_{Y}	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V	V _{OL} + 0.1 V	V _{OL} + 0.1 V		

9. For V_{mi} : $V_{CCI} = V_{CCA}$ for Control Pin T/ \overline{R} or V_{CCA} / 2.

ORDERING INFORMATION

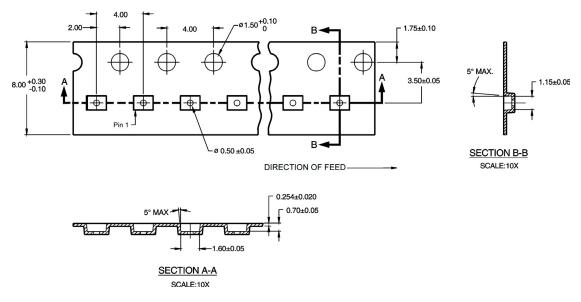
Order Number	Case Number	Pb-Free	Package Description	Supplied As
FXLH1T45L6X	127EB	Yes	6-Lead MicroPak/SIP6, 1.0 mm Wide	5k Units on Tape and Reel

Tape and Reel Specification

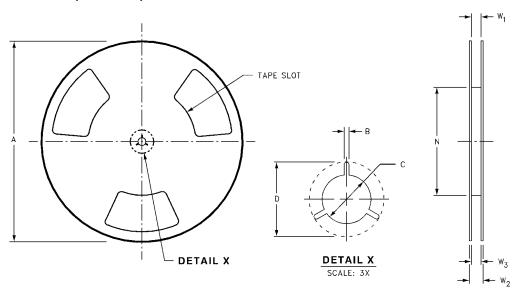
TAPE FORMAT FOR MICROPAK

Package Designator	Tape Section	Number Cavities	Cavity Status	Cover Tape Status
L6X	Leader (Start End)	125 (typ)	Empty	Sealed
	Carrier	5000	Filled	Sealed
	Trailer (Hub End)	75 (typ)	Empty	Sealed

Tape Dimensions Millimeters

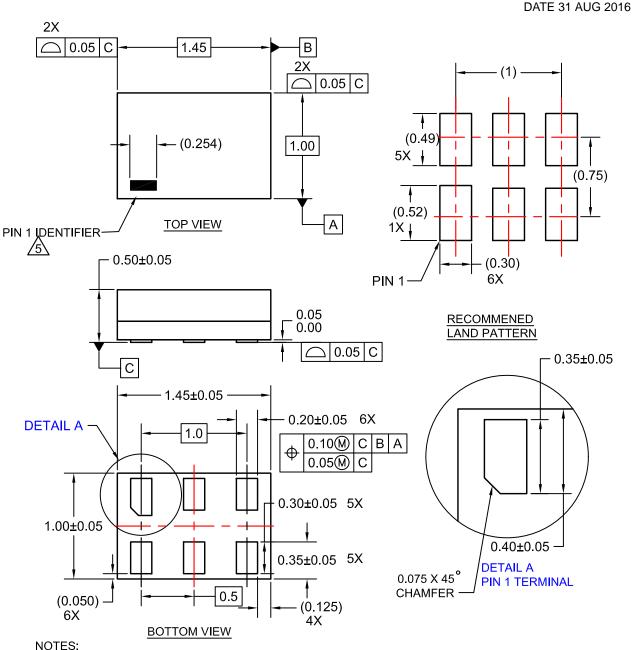


Reel Dimensions Inches (Millimeters)



Tape Size	Α	В	С	D	N	W1	W2	W3
8 mm	7.0	0.059	0.512	0.795	2.165	0.331 + 0.059/-0.000	0.567	W1 + 0.078 /-0.039
	(177.8)	(1.50)	(13.00)	(20.20)	(55.00)	(8.40 + 1.50 /-0.00)	(14.40)	(W1 + 2.00 /-1.00)





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